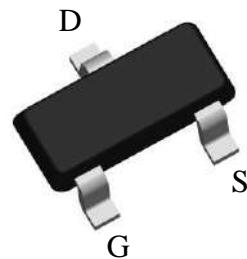


N-Channel Enhancement Mode MOSFET

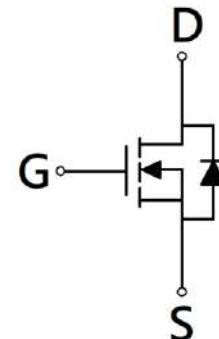
Features:

- Low On Resistance
- Low Gate Charge
- Fast Switching Characteristic

SOT-23



BV_{DSS}	20V
$I_D @ V_{GS} = 4.5V, T_A = 25^\circ C$	3.5A
$R_{DS(ON)} \text{ typ.} @ V_{GS} = 4.5V, I_D = 3A$	29m Ω
$R_{DS(ON)} \text{ typ.} @ V_{GS} = 2.5V, I_D = 2A$	39m Ω



G : Gate S : Source D : Drain

Ordering Information

Device	Package	Shipping
KWN2302	SOT-23 (Pb-free lead plating and halogen-free package)	3000 pcs / Tape & Reel



Absolute Maximum Ratings ($T_A=25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 8	
Continuous Drain Current @ $V_{GS}=4.5\text{V}$, $T_A=25^\circ\text{C}$	I_D	3.5	A
Continuous Drain Current @ $V_{GS}=4.5\text{V}$, $T_A=70^\circ\text{C}$		2.8	
Pulsed Drain Current	I_{DM}	14	
Continuous Body Diode Forward Current @ $T_A=25^\circ\text{C}$	I_S	1	W
Total Power Dissipation		1.3	
$T_A=70^\circ\text{C}$		0.8	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150	°C

Thermal Data

Parameter	Symbol	Steady State	Unit
Thermal Resistance, Junction-to-ambient	$R_{\theta JA}$	100	°C/W

Note:

*a. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in² FR -4 board with 2 oz. copper, in a still air environment with $T_A=25^\circ\text{C}$. The power dissipation P_D is based on $R_{\theta JA}$ and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.

*b. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^\circ\text{C}$. Ratings are based on low frequency and low duty cycles to keep initial $T_J=25^\circ\text{C}$.

Electrical Characteristics ($T_A=25^\circ\text{C}$, unless otherwise specified)

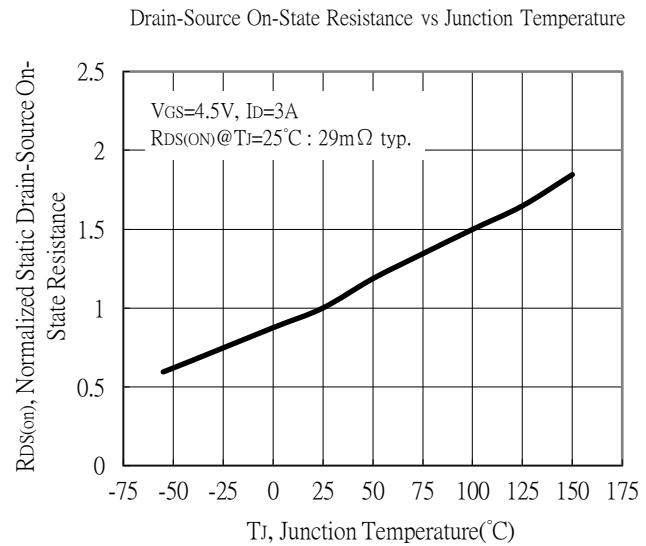
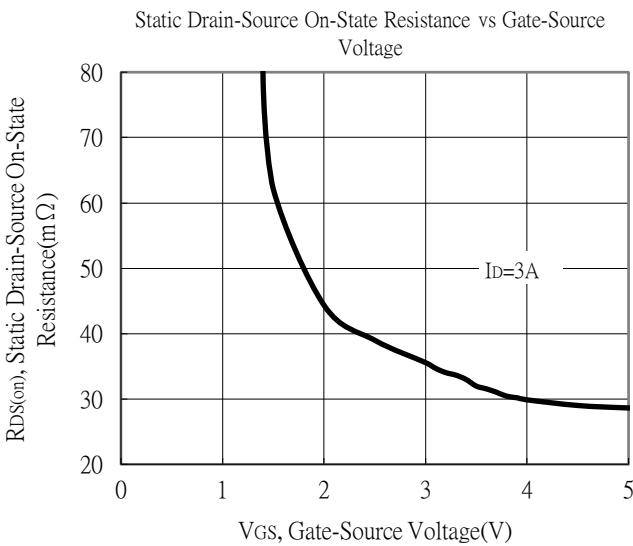
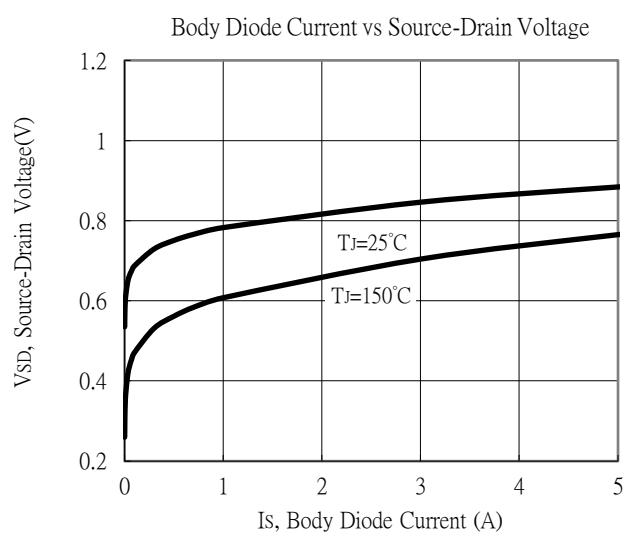
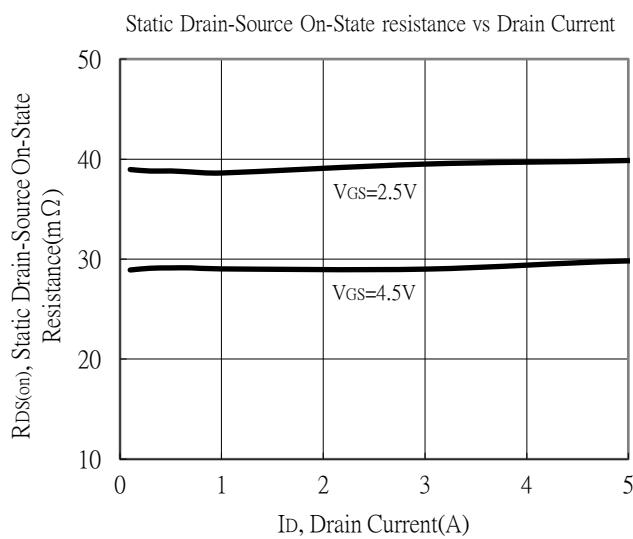
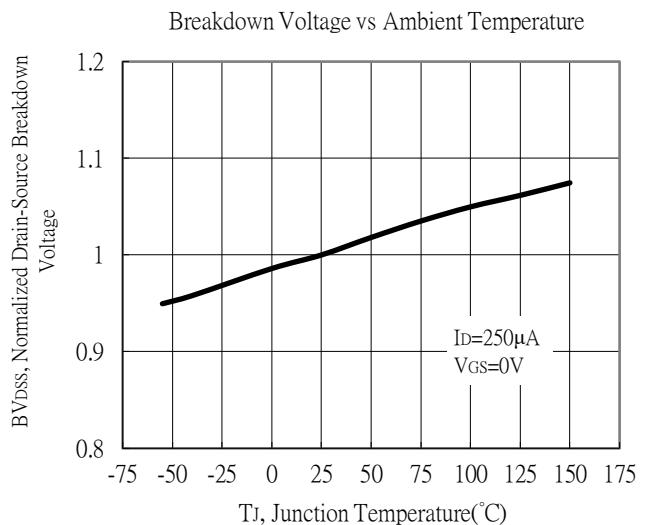
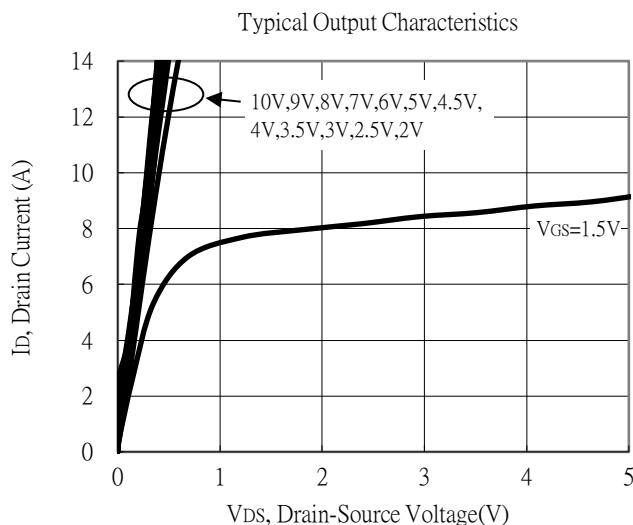
Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV _{DSS}	20	-	-	V	V _{GS} =0V, I _D =250μA
V _{GS(th)}	0.5	-	1.2		V _{DS} =V _{GS} , I _D =250μA
G _{FS}	-	7	-	S	V _{DS} =5V, I _D =3A
I _{GSS}	-	-	±100	nA	V _{GS} =±8V, V _{DS} =0V
I _{DSS}	-	-	1	μA	V _{DS} =16V, V _{GS} =0V
R _{DSS(ON)}	-	29	55	mΩ	V _{GS} =4.5V, I _D =3A
	-	39	70		V _{GS} =2.5V, I _D =2A
Dynamic					
C _{iss}	-	470	-	pF	V _{DS} =10V, V _{GS} =0V, f=1MHz
C _{oss}	-	65	-		
C _{rss}	-	60	-		
R _g	-	1.2	-	Ω	f=1MHz
Q _g *1, 2	-	6.4	-	nC	V _{DS} =10V, I _D =3A, V _{GS} =4.5V
Q _{gs} *1, 2	-	0.7	-		
Q _{gd} *1, 2	-	1.7	-		
t _{d(ON)} *1, 2	-	4.5	-	ns	V _{DS} =10V, I _D =3A, V _{GS} =5V, R _{GS} =6Ω
t _r *1, 2	-	14	-		
t _{d(OFF)} *1, 2	-	30	-		
t _f *1, 2	-	8.5	-		
Source-Drain Diode					
V _{SD} *1	-	0.89	1.2	V	I _S =3A, V _{GS} =0V
trr	-	6	-	ns	I _F =3A, dI _F /dt=100A/μs
Qrr	-	2	-	nC	

Note:

*1. Pulse Test : Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

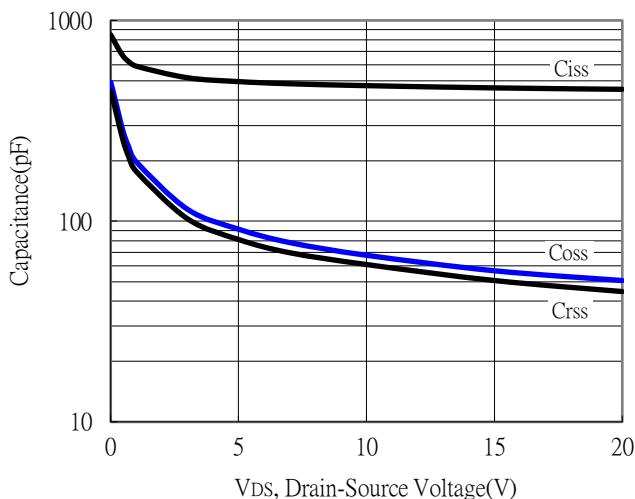
*2. Independent of operating temperature

Typical Characteristics

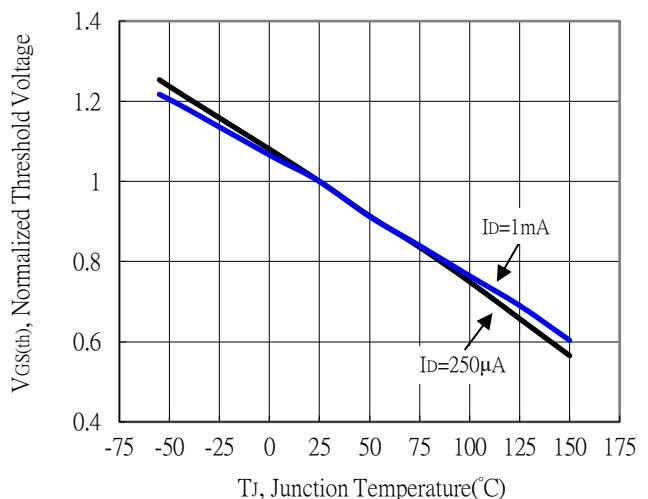


Typical Characteristics (Cont.)

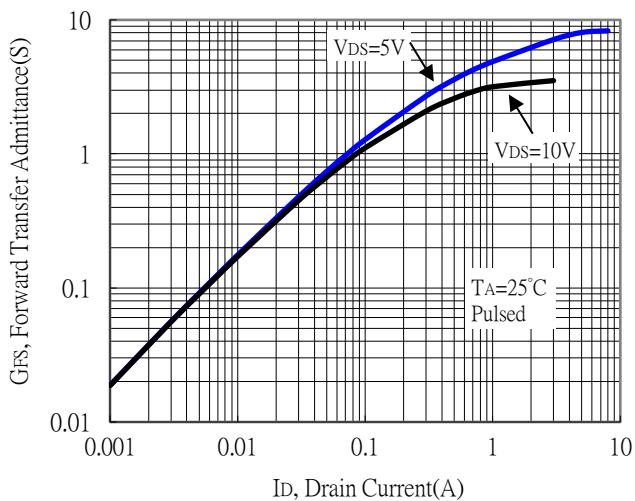
Capacitance vs Drain-to-Source Voltage



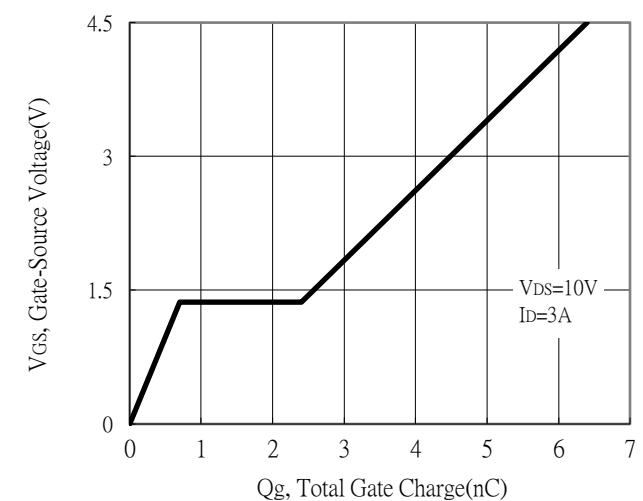
Threshold Voltage vs Junction Temperature



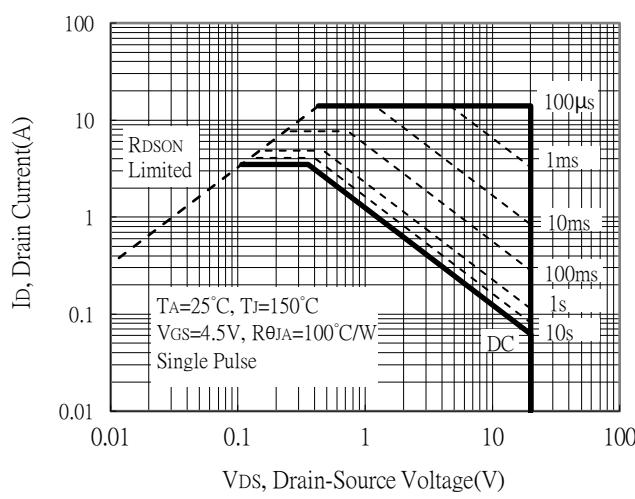
Forward Transfer Admittance vs Drain Current



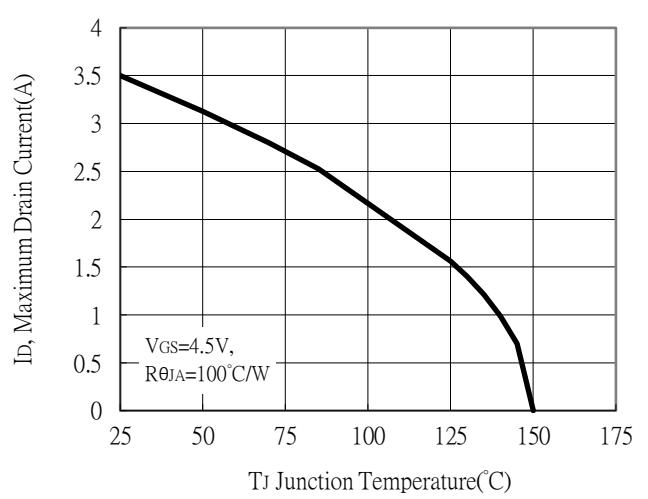
Gate Charge Characteristics



Maximum Safe Operating Area

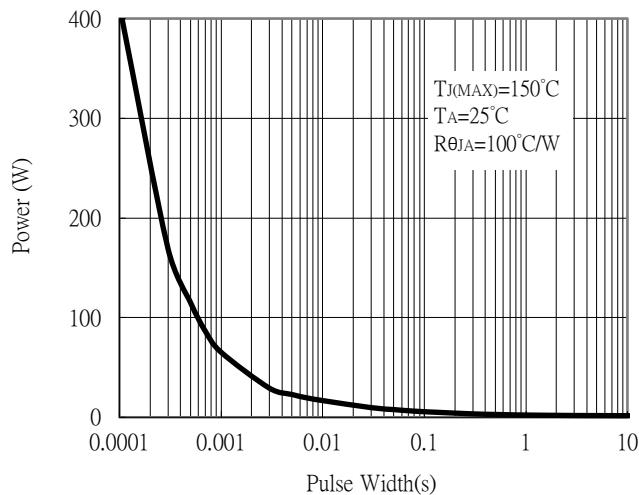


Maximum Drain Current vs Junction Temperature

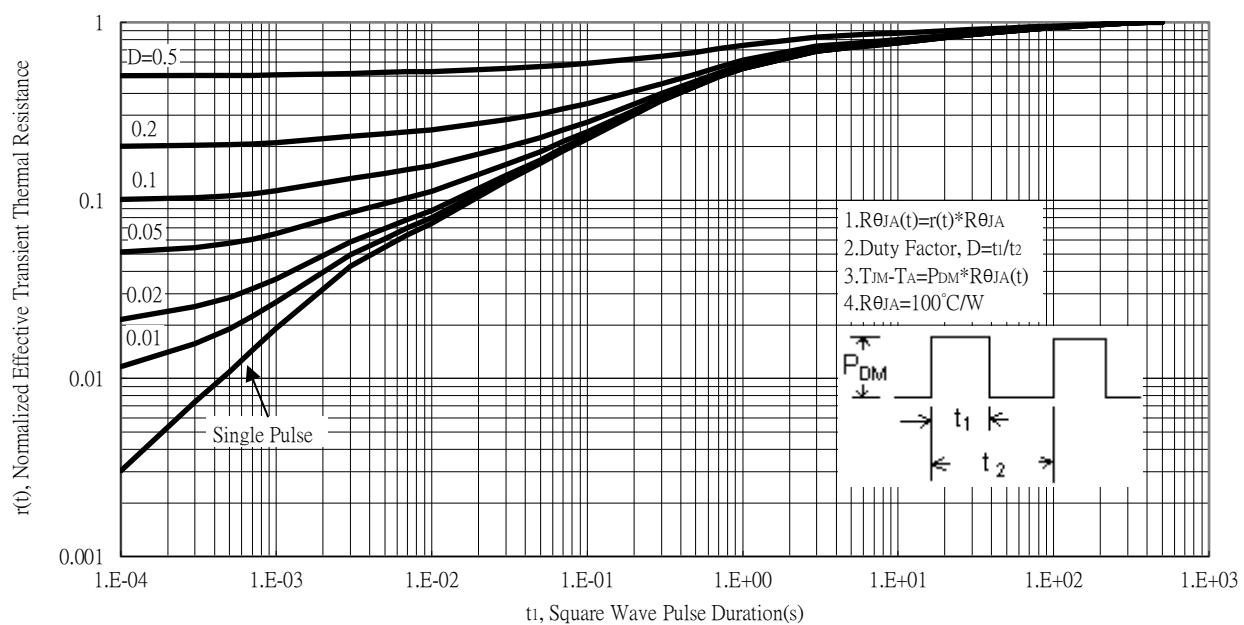


Typical Characteristics (Cont.)

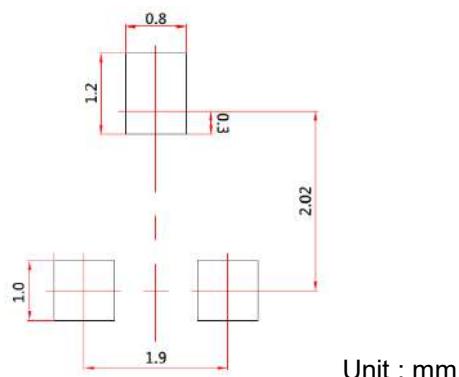
Single Pulse Power Rating, Junction to Ambient



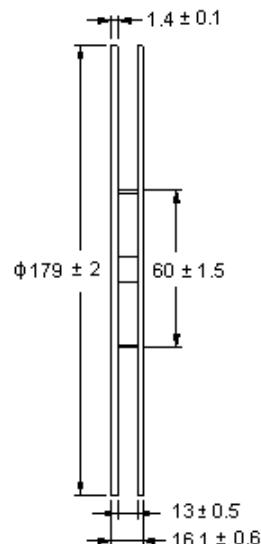
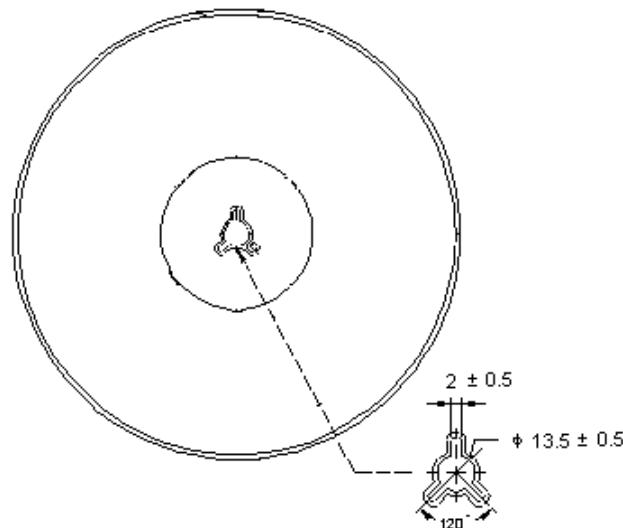
Transient Thermal Response Curves



Recommended Soldering Footprint

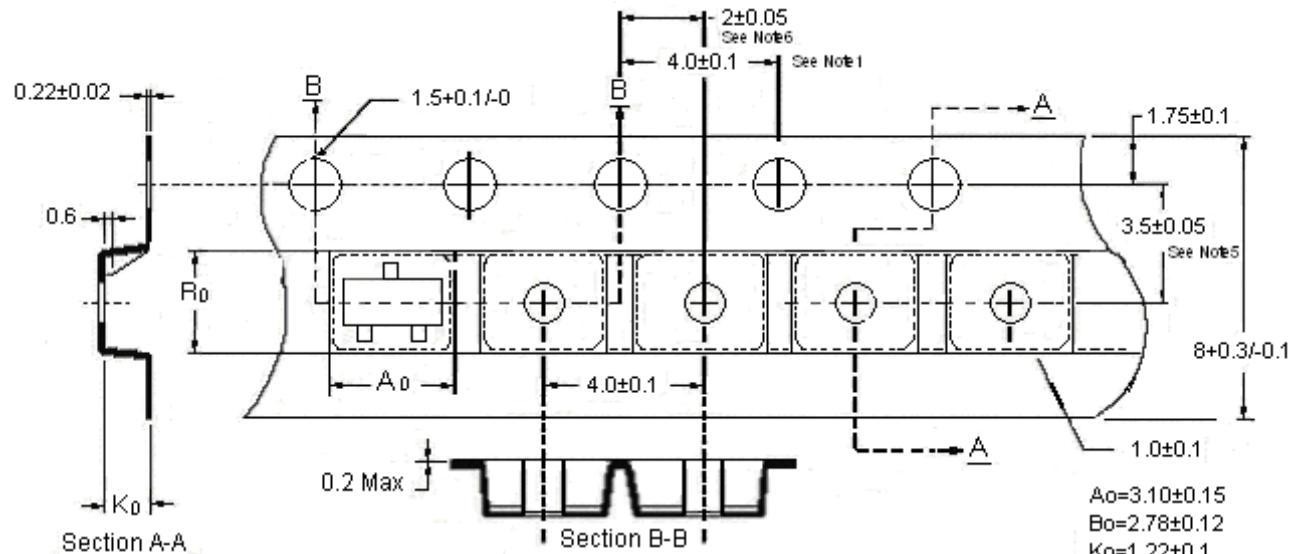


Reel Dimension



Unit: millimeter

Carrier Tape Dimension

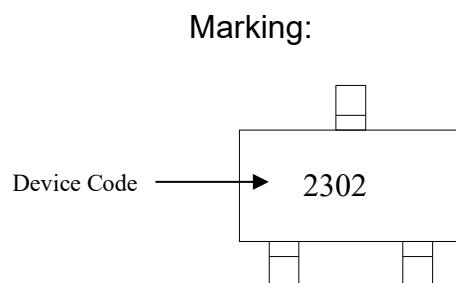
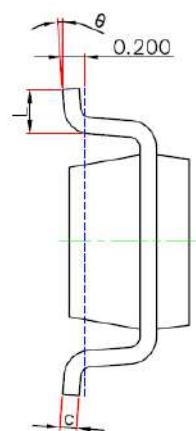
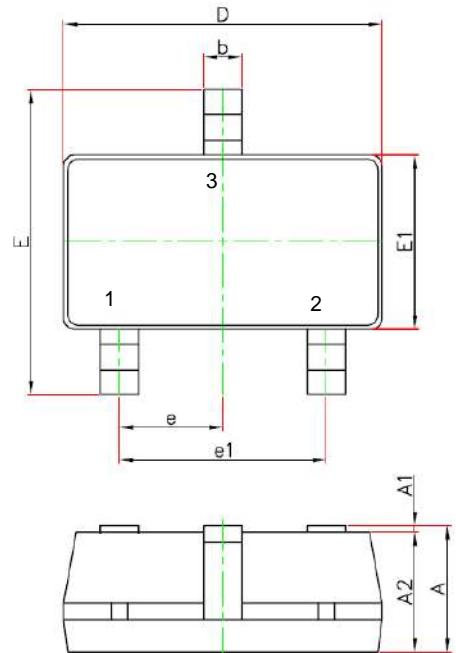


Notes:

1. 10 sprocket hole pitch cumulative tolerance ± 0.2 .
2. Camber not to exceed 1mm in 100mm.
3. Material : conductive Black Polystyrene.
4. Ao & Bo measured on a plane 0.3mm above the bottom of the pocket.
5. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.

Unit : millimeter

SOT-23 Dimension



Style: Pin 1.Gate 2.Source 3.Drain

3-Lead SOT-23 Plastic Surface Mounted Package

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.035	0.049	0.90	1.25	E1	0.047	0.067	1.20	1.70
A1	0.000	0.004	0.00	0.10	E	0.089	0.116	2.25	2.95
A2	0.041	0.045	1.05	1.15	e	0.037 BSC		0.95 BSC	
b	0.012	0.020	0.30	0.50	e1	0.071	0.079	1.80	2.00
c	0.003	0.008	0.08	0.20	L	0.012	0.024	0.30	0.60
D	0.110	0.119	2.80	3.02	θ	0 °	8 °	0 °	8 °